

4.3 Semiconductors

4.4 Electron effective mass

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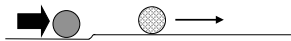
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1

Conductor (metal):



The electron is like a ball rolling on almost flat ground:



Electron can move easily

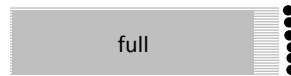
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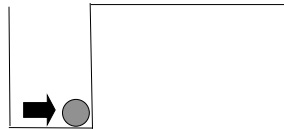
2

Insulator:

ENERGY gap- no ALLOWED levels



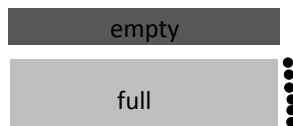
Electron is in a pit,



It can't move without a big boost.

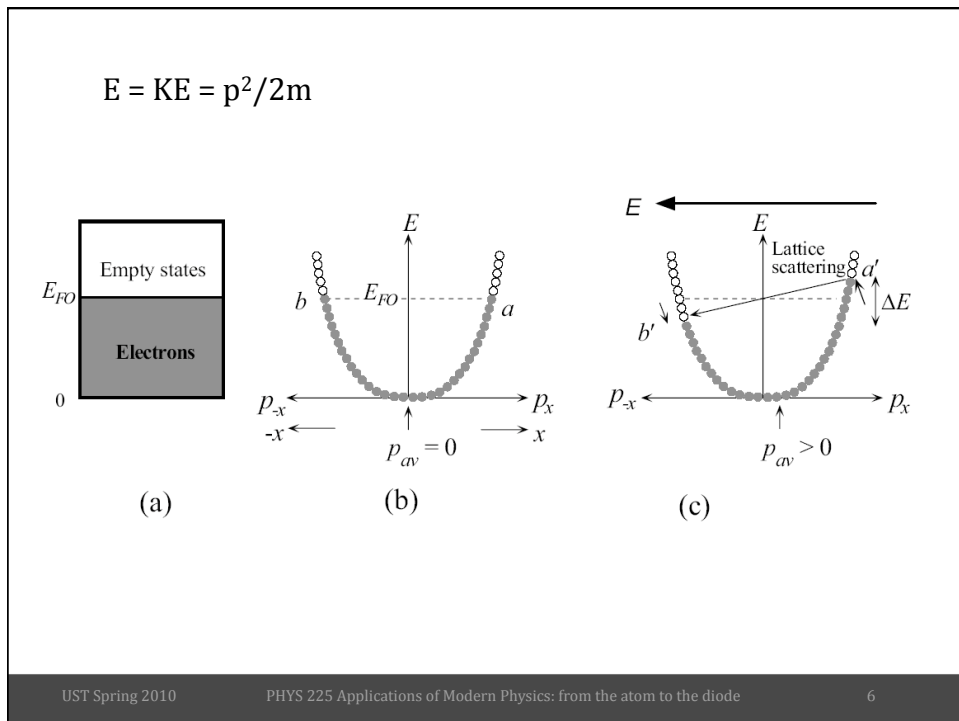
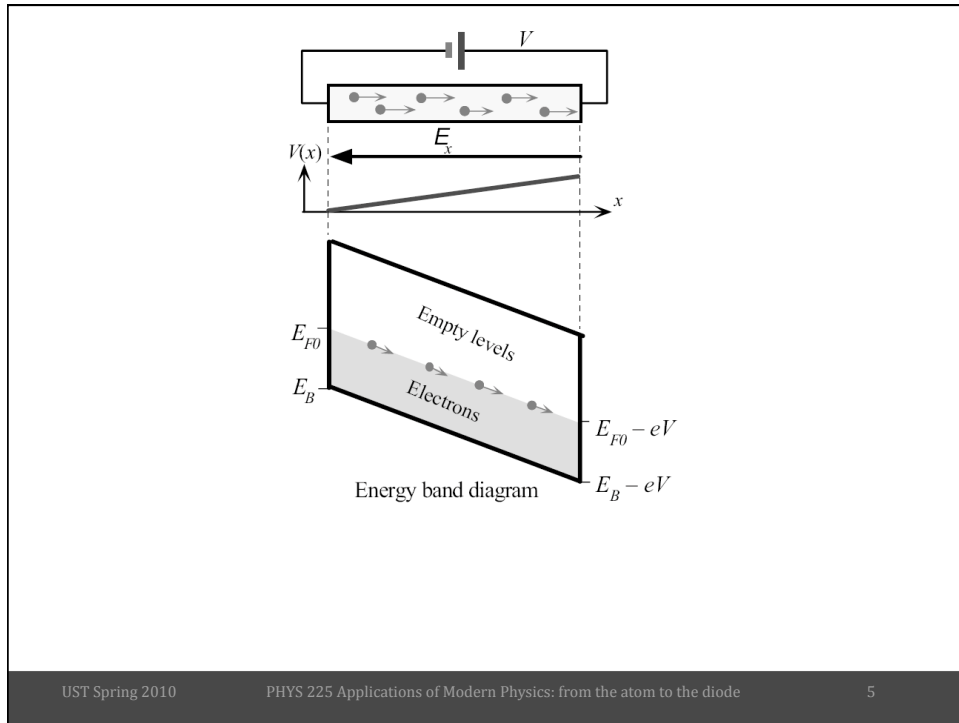
Semiconductor:

Half way in between a conductor and an insulator.



Little gap to empty levels, shallow pit.





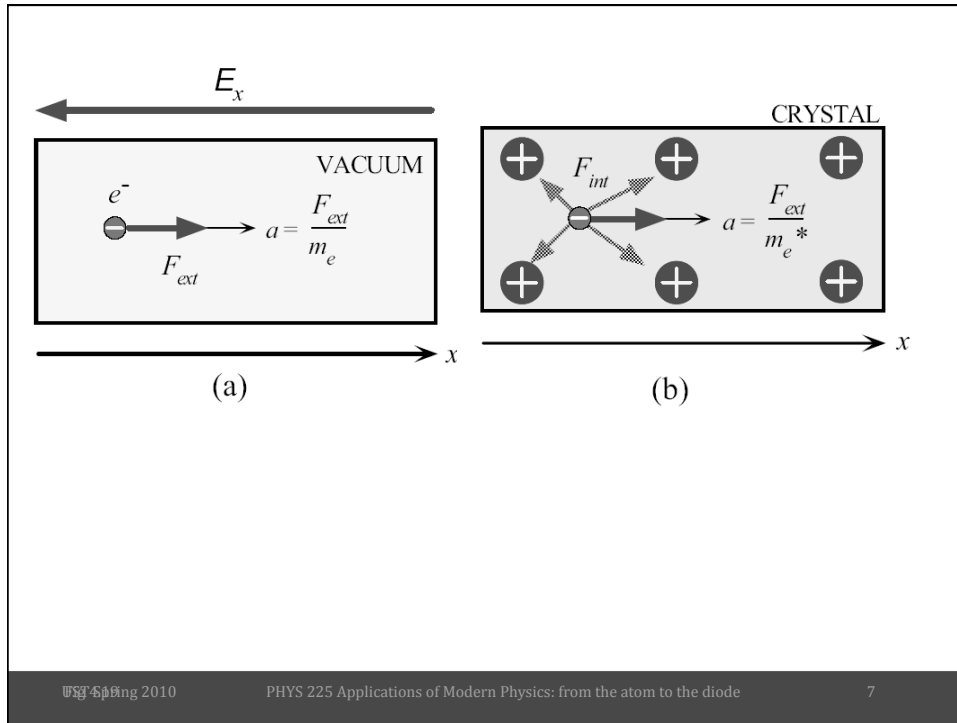


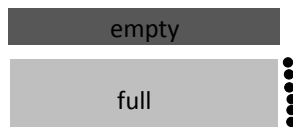
Table 4.2 Effective mass m_e^* of electrons in some metals

Metal	Ag	Au	Bi	Cu	K	Li	Na	Ni	Pt	Zn
$\frac{m_e^*}{m_e}$	0.99	1.10	0.047	1.01	1.12	1.28	1.2	28	13	0.85

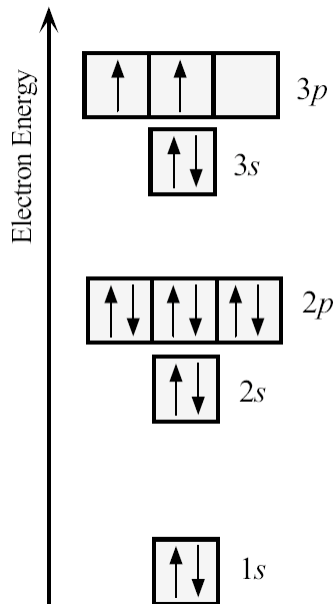
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Semiconductor:

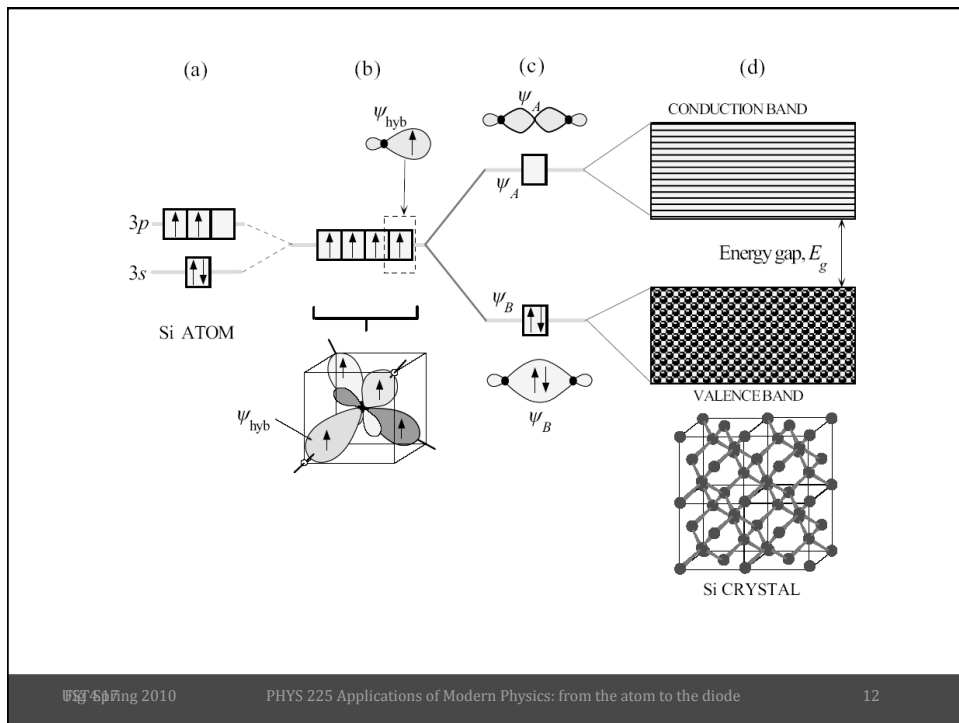
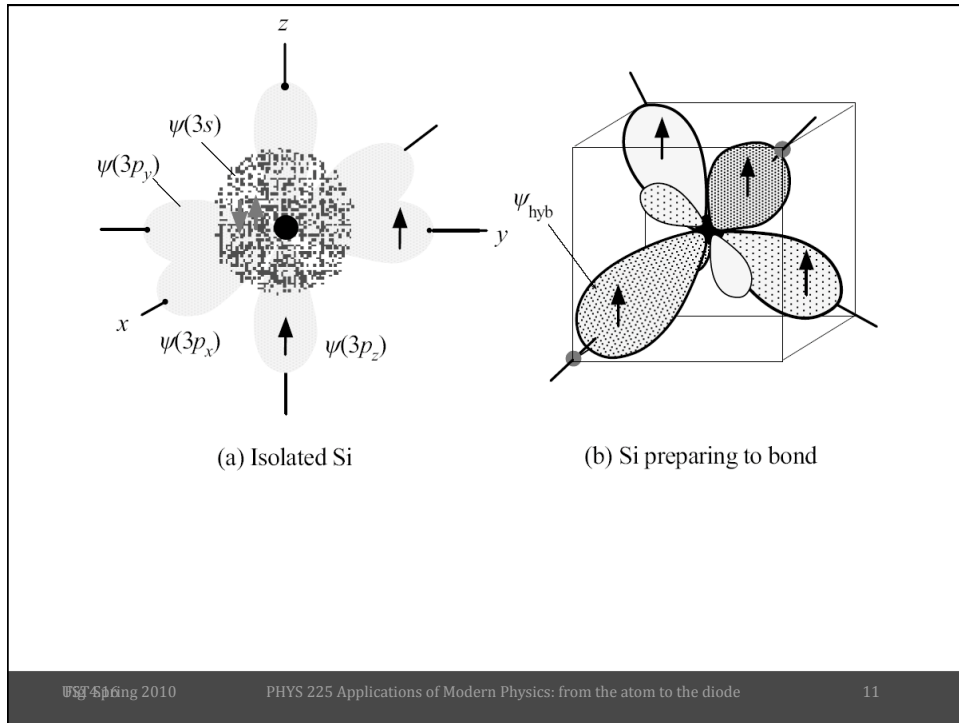
Half way in between a conductor and an insulator.

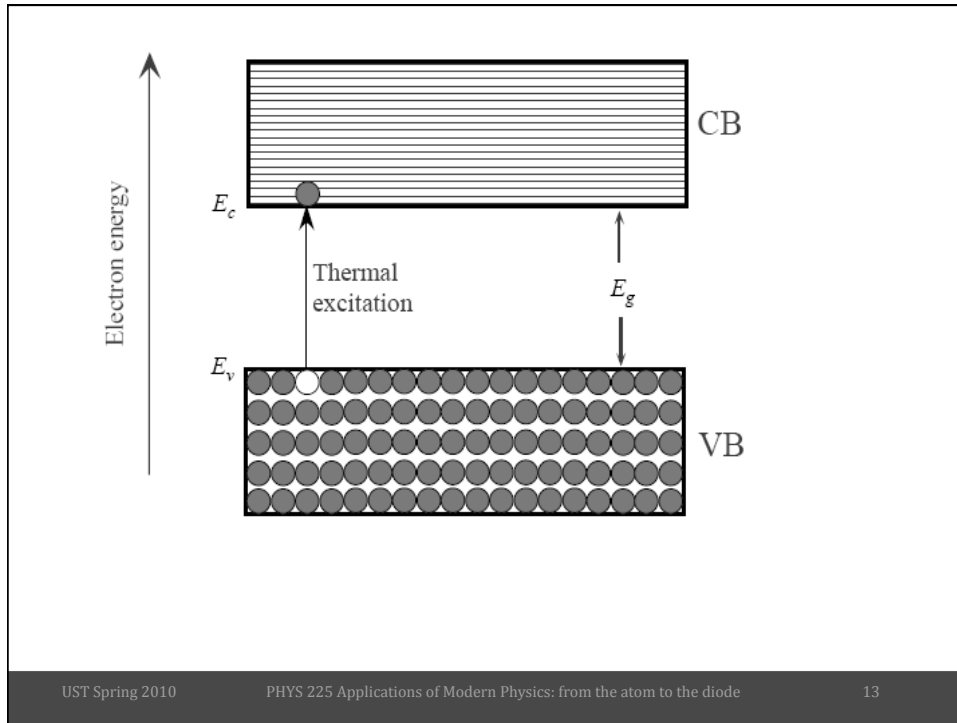


Little gap to empty levels, shallow pit.



The electronic structure of Si





Semiconductors:

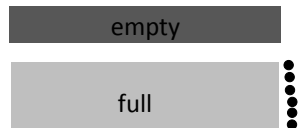
									VIIIA
									² He 4.003
		IIIA	IVA	VA	VIA	VIIA			¹⁰ Ne 20.183
		5 B 10.811	6 C 12.011	7 N 14.007	8 O 15.999	9 F 18.998			
		13 Al 26.982	14 Si 28.086	15 P 30.974	16 S 32.064	17 Cl 35.453			¹⁸ Ar 39.948
IB	IIB								
29 Cu 63.54	30 Zn 65.37	31 Ga 69.72	32 Ge 72.59	33 As 74.922	34 Se 78.96	35 Br 79.909			³⁶ Kr 83.80
47 Ag 107.870	48 Cd 112.40	49 In 114.82	50 Sn 118.69	51 Sb 121.75	52 Te 127.60	53 I 126.904			⁵⁴ Xe 131.30
79 Au 196.967	80 Hg 200.59	81 Tl 204.37	82 Pb 207.19	83 Bi 208.980	84 Po (210)	85 At (210)			⁸⁶ Rn (222)

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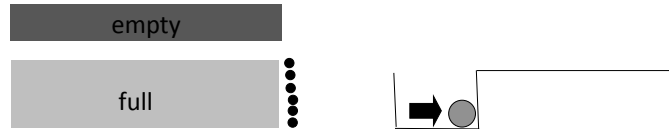
Material	Band gap [ev] (T = 0K)	Band gap [ev] (T = 300K)
Si	1.17	1.11
Ge	0.74	0.66
InSb	0.23	0.17
InAs	0.43	0.36
InP	1.42	1.27
GaP	2.32	2.25
GaAs	1.52	1.43
GaSb	0.81	0.68
CdSe	1.84	1.74
CdTe	1.61	1.44
ZnO	3.44	3.2
ZnS	3.91	3.6
C (diamond)		5.5

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Semiconductors:.



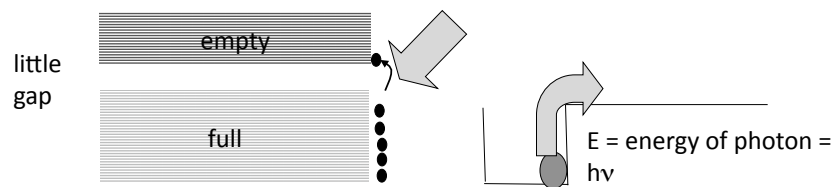
What are possible ways could get electron to higher empty level (out of pit), so could move to conduct electricity?



Ways to get electrons up to where they can move:

1. light-- photoconductors (copying machines, laser printers)
2. heat
3. designer impurities- tinker slightly with energy levels.

1. Photoconductors:



Physics of copying machines and laser printers.

1

2

Charge image

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